



HAT2170H-EL-E Information



For Reference Only

Part Number HAT2170H-EL-E

ManufacturerRenesas Electronics AmericaCategoryDiscrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 40V 45A LFPAK

Package SC-100, SOT-669

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









HAT2170H-EL-E Specifications

Manufacturer Part Number	HAT2170H-EL-E
Manufacturer	Renesas Electronics America
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SC-100, SOT-669
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	45A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	7V, 10V
Vgs(th) (Max) @ Id	3V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	62nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4650pF @ 10V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	30W (Tc)
Rds On (Max) @ Id, Vgs	4.2 mOhm @ 22.5A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	LFPAK
Package / Case	SC-100, SOT-669
	Report errors?

HAT2170H-EL-E Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

HAT2170H-EL-E Payment Methods



















HAT2170H-EL-E Shipping Methods













If you have any question about HAT2170H-EL-E, please do not hesitate to contact us!

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